Reflectionless Band Pass Filter Die

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50Ω 15.5 to 20.5 GHz

The Big Deal

- High Stopband rejection, up to 77 dB
- Patented design terminates stopband signals
- Stop band up to 40 GHz
- Excellent repeatability through IPD* process

Product Overview

Mini-Circuits' XBF-D-Series are GaAs MMIC reflectionless filters which includes 4-sections, giving you ultra-high rejection in the stopband – up to 77 dB! Reflectionless filters employ a patented filter topology which absorbs and terminates stopband signals internally rather than reflecting them back to the source. This new capability enables unique applications for filter circuits beyond those suited to traditional approaches. Traditional filters are reflective in the stopband, sending signals back to the source at 100% power.

These reflections interact with neighboring components and often result in intermodulation and other interferences. By eliminating stopband reflections, reflectionless filters can readily be paired with sensitive devices and used in applications that otherwise require circuits such as isolation amplifiers or attenuators.

Key Features	Advantages		
Choice of BW 15.5 - 16.5 GHz 17.5 - 18.5 GHz 19.5 - 20.5 GHz	Three different models to cover the band XBF-183-D+ XBF-183-D+ XBF-24-D+		
Easy integration with sensitive reflective components, e.g. mixers, multipliers	Reflectionless filters absorb unwanted signals, preventing reflections back to the source. This reduces generation of additional unwanted signals without the need for extra components like attenuators, improving system dynamic range and saving board space.		
High stopband rejection, up to 77 dB	Ideal for applications where suppression of strong spurious signals and intermod- ulation products is needed.		
Enables stable integration of wideband amplifiers	Because reflectionless filters maintain good impedance in the stop band; they can be integrated with high gain, wideband amplifiers without the risk of creating instabilities in these out of band regions.		
Cascadable	Reflectionless filters can be cascaded in multiple sections to provide sharper and higher attenuation, while also preventing any standing waves that could affect pass band signals.		
Excellent power handling in a tiny surface mount device up to 0.5W in passband	High power handling extends the usability of these filters to the transmit path for inter-stage filtering.		
Unpackaged die	Enables the user to integrate the filter directly into hybrids		
Excellent repeatability of RF performance	Through semiconductor IPD process, X-series filters are inherently repeatable for large volume production.		
Operating temperature up to 105°C	Suitable for operation close to high power components.		

*IPD - Integrated Passive Device, is a GaAs semiconductor process

Reflectionless **Band Pass Filter Die**

XBF-183-D+

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

Ordering Information: Refer to Last Page

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50Ω 17.5 to 18.5 GHz

Features

- Match to 50Ω in the stop band, eliminates undesired reflections
- Cascadable
- Excellent stopband rejection, 50 dB typ.
- Temperature stable, up to 105°C
- Protected by US Patents 8,392,495; 9,705,467, additional patent pending
- Protected by China Patent 201080014266.1
- Protected by Taiwan Patent I581494

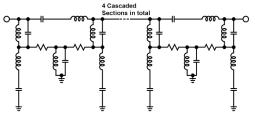
Applications

- Transmitters & Receivers
- Harmonic Rejection
- Spurious Rejection

General Description

Mini-Circuits' XBF-183-D+ four-section reflectionless filter Die employs a novel filter topology which absorbs and terminates stop band signals internally rather than reflecting them back to the source. This new capability enables unique applications for filter circuits beyond those suited to traditional approaches. Traditional filters are reflective in the stop band, sending signals back to the source at 100% of the power level. These reflections interact with neighboring components and often result in inter-modulation and other interferences. Reflectionless filters eliminate stop band reflections, allowing them to be paired with sensitive devices and used in applications that otherwise require circuits such as isolation amplifiers or attenuators.

Simplified Schematic and Pad description



Pad#	Description
2	RF-IN
5	RF-OUT
1,3,4,6	Ground
Die bottom	Ground

Note: 1. Bond Pad material - Gold 2. Bottom of Die - Gold plated

Bonding Pad Position



	Dimensions in µm, Typical											
ſ	L1	L2	L3	L4	L5	H1	H2	H3	H4	H5	Thickness	Bond pad size
	80	2370	2470	2570	2650	80	550	650	750	1300	100	78 X 78



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Electrical Specifications¹ at 25°C

Param	eter	F#	Frequency (MHz)	Min.	Тур.	Max.	Unit
Pass Band	Insertion Loss	F2-F3	17500 - 18500		4.3		dB
Pass Band	VSWR	F2-F3	17500 - 18500		1.9		:1
Stop Band, Lower	Rejection	DC-F1	DC - 9000		77		dB
Stop Ballu, Lower	VSWR	DC-F1	DC - 9000		1.2		:1
	Rejection	F4-F5	27000 - 32000		50		dB
Stop Band, Upper	riejection	F5-F6	32000 - 40000		51		UD
otop Band, Opper	VSWR	F4-F5	27000 - 32000		1.5		:1
	VOVIII	F5-F6	32000 - 40000		1.2		

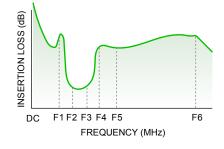
¹ Measured on die using MPI titan series 100µm pitch GSG probe.

Absolute Maximum Ratings⁴

Parameter	Ratings
Operating Temperature	-55°C to +105°C
RF Power Input, Passband (F2-F3) ²	0.5W at 25°C
RF Power Input, Stopband (DC-F2, F3-F6) ³	0.16W at 25°C

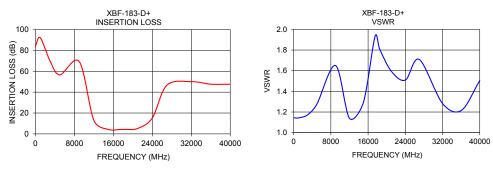
² Passband rating derates linearly to 0.25W at 105°C ambient
 ³ Stopband rating derates linearly to 0.08W at 105°C ambient
 ⁴ Permanent damage may occur if any of these limits are exceeded.

Specification Definition



Iy	Typical Performance Data at 25°C				
Frequency (MHz)	Insertion Loss (dB)	VSWR (:1)			
 10	83.55	1.14			
100	85.36	1.14			
1000	92.05	1.14			
3000	69.77	1.17			
5000	56.59	1.28			
9000	69.15	1.65			
12000	12.78	1.14			
15000	4.23	1.29			
17500	4.30	1.93			
18500	4.30	1.81			
21000	5.27	1.59			
24000	15.31	1.51			
27000	46.71	1.71			
32000	50.04	1.28			
36000	47.63	1.21			
40000	47.55	1.50			

Typical Darformonae Data at 25°C

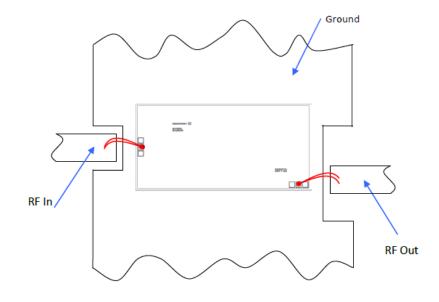


⊒Mini-Circuits⁵

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Assembly Diagram



Note: Ground bond wires are optional.

Assembly and Handling Procedure

1. Storage

Dice should be stored in a dry nitrogen purged desiccators or equivalent.

2. ESD

MMIC Gallium Arsenide (GaAs) filter dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static worksta tion. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.

3. Die Attach

The Die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are DieMat DM6030Hk-PT/H579/H579 or Ablestik 84-1LMISR4. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total Die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufac turer's cure condition. It is recommended to use antistatic Die pick up tools only.

4. Wire Bonding

Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the Die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.



Additional Detailed Technic additional information is available on our		
	Data Table	
Performance Data	Swept Graphs	
	S-Parameter (S2P Files) Data Set wit	th and without port extension(.zip file)
Case Style	Die	
	Quantity, Package	Model No.
	Small, Gel - Pak: 5,10,50,100 KGD*	
Die Ordering and packaging information	Medium [†] , Partial wafer: KGD*<605	XBF-183-DP+
	[†] Available upon request contact sales	s representative
	Refer to AN-60-067	
Environmental Ratings	ENV-80	

*Known Good Dice ("KGD") means that the dice are taken from PCM good wafer and visually inspected in question have been subjected to Mini-Circuits while this is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

ESD Rating**

Human Body Model (HBM): Class 1C (Pass 1000V) in accordance with ANSI/ESD STM 5.1 - 2001

** Tested in industry standard MCLP 4x4mm, 24-lead package.

Additional Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
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Typical Performance Data

	Test Condition @ Temperature = +25°C						
FREQ.	INSERTION LOSS	INPUT RETURN LOSS	OUTPUT RETURN LOSS				
(MHz)	(dB)	(dB)	(dB)				
10	83.55	23.40	25.14				
50	86.15	23.41	25.14				
100	85.36	23.43	25.16				
200	88.13	23.45	25.18				
300	94.32	23.45	25.20				
400	91.74	23.48	25.23				
500	91.19	23.49	25.25				
600	90.63	23.50	25.25				
700	98.35	23.51	25.26				
800	93.25	23.53	25.27				
900	92.65	23.53	25.26				
1000	92.05	23.54	25.24				
2000	80.51	23.20	24.43				
3000	69.77	22.01	22.60				
4000	61.70	20.18	20.43				
5000	56.59	18.31	18.37				
6000	54.16	16.35	16.48				
7000	55.28	14.57	14.86				
8000	64.16	13.09	13.71				
9000	69.15	12.20	13.28				
10000	68.76	12.82					
			14.55				
11000	31.94	19.78	20.56				
12000	12.78	32.12	23.76				
13000	6.73	19.63	19.98				
14000	4.90	18.73	21.81				
15000	4.23	17.85	18.15				
16000	4.10	14.26	13.16				
17000	4.24	11.36	10.44				
17500	4.30	10.77	9.94				
17600	4.31	10.73	9.91				
17700	4.32	10.72	9.90				
17800	4.33	10.72	9.92				
17900	4.33	10.77	9.97				
18000	4.33	10.84	10.05				
18100	4.33	10.96	10.14				
18200	4.33	11.09	10.26				
18300	4.32	11.28	10.20				
18400	4.31	11.49	10.60				
	4.30	11.49					
18500			10.82				
19000	4.23	13.96	12.55				
20000	4.37	21.79	17.36				
21000	5.27	13.88	12.80				
22000	6.67	13.59	12.56				
23000	9.45	16.84	14.97				
24000	15.31	15.11	13.86				
25000	25.78	14.12	13.07				
26000	40.18	12.16	11.78				
27000	46.71	11.65	11.98				
28000	48.36	12.10	13.13				
29000	52.88	13.11	14.89				
30000	51.66	14.46	17.25				
31000	51.25	16.18	20.20				
32000	50.04	18.17	23.38				
33000	51.60	20.20	24.96				
34000	51.79	21.92	23.99				
35000	49.88	21.32	23.39				
36000	47.63	21.52	20.29				
37000	47.83 50.82	19.96	18.84				
38000	51.38	18.29	17.68				
39000	50.52	16.56	16.50				
40000	47.55	13.92	14.95				

Test Condition @ Temperature = +25°C

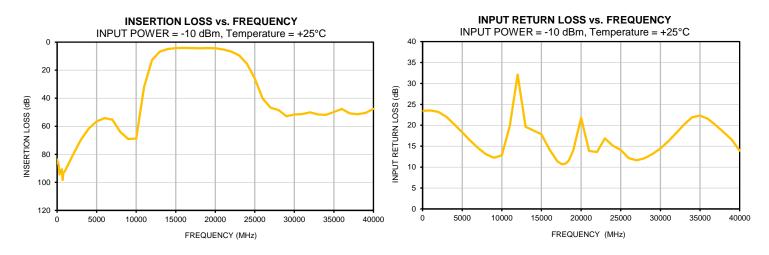




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Typical Performance Curves



OUTPUT RETURN LOSS vs. FREQUENCY INPUT POWER = -10 dBm, Temperature = +25°C 40 35 30 OUTPUT RETURN LOSS (dB) 25 20 15 10 5 0 0 . 5000 10000 15000 20000 25000 30000 35000 40000 FREQUENCY (MHz)





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All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
Operating Temperature	-40° to 85° C or -40° to 105° C or -55° to 105° C or -45° to 105° C Ambient Environment	Refer to Individual Model Data Sheet
Storage Environment (Die)	-65° to 150°C	Individual Model Data Sheet
Storage Environment(Packaging)	-40° to 70°C and 40 to 60% humidity (In Factory Shipped Package)	

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